NSN 5961-00-037-9524



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-037-9524 **Inclosure Material:** Metal **Overall Length:** 0.468 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-59 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to emitter reverse voltage, with base short-circuited to emitter and 80.0 collector to emitter voltage/static/base open and 5.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 2.00 amperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Test Data Document:

24930-g390302s1 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

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NSN 5961-00-037-9524 Transistor - Page 2 of 2



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